	Application No.	Applicant(s)
Notice of Allowability	10/049,715	HASHIGUCHI ET AL.
	Examiner	Art Unit
	Dung Nguyen	2871
The MAILING DATE of this communication apperature All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIOF the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in or other appropriate communing GHTS. This application is sure and MPEP 1308.	this application. If not included nication will be mailed in due course. THIS ubject to withdrawal from issue at the initiativ
1. X This communication is responsive to <u>responseand English</u>	translation dated 07/08/2004	ļ.
2. \boxtimes The allowed claim(s) is/are <u>1,2 and 7</u> .		
3. $igotimes$ The drawings filed on <u>05 January 2004</u> are accepted by the	e Examiner.	
4. Acknowledgment is made of a claim for foreign priority una) All b) Some* c) None of the: 1. Certified copies of the priority documents have 2. Certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)). * Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 5. A SUBSTITUTE OATH OR DECLARATION must be submit INFORMAL PATENT APPLICATION (PTO-152) which give 1. CORRECTED DRAWINGS (as "replacement sheets") mus (a) including changes required by the Notice of Draftspers 1) hereto or 2) to Paper No./Mail Date (b) including changes required by the attached Examiner's Paper No./Mail Date	been received. been received in Application cuments have been received of this communication to file at ENT of this application. itted. Note the attached EXAL is reason(s) why the oath or at the submitted. on's Patent Drawing Review at Amendment / Comment or it	in No in this national stage application from the a reply complying with the requirements MINER'S AMENDMENT or NOTICE OF declaration is deficient. (PTO-948) attached In the Office action of
Identifying indicia such as the application number (see 37 CFR 1. each sheet. Replacement sheet(s) should be labeled as such in the deposition of the deposi	ne header according to 37 CFF	R 1.121(d).
attached Examiner's comment regarding REQUIREMENT I		
Attachment(s)	5 Nation of lufe	armal Datast Application (DTO 450)
 Notice of References Cited (PTO-892) Notice of Draftperson's Patent Drawing Review (PTO-948) 	5. ☐ Notice of Info	ormal Patent Application (PTO-152)
 Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 02/2002 	Paper No./N	Mail Date Amendment/Comment
4. Examiner's Comment Regarding Requirement for Deposit	8. 🛛 Examiner's S	Statement of Reasons for Allowance
of Biological Material	9. 🗌 Other	•

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DETAILED ACTION

Applicants' request for reconsideration and an English translation paper dated 07/08/2004 has been received and entered.

Claims 1, 2 and 7 are still pending in the application.

Examiner's Amendment

In view of the Examiner's restriction requirement dated 06/17/2003 and subsequent election dated 07/03/2003, claims 3-6 and 8-9 have been withdrawn from consideration, and they are now canceled by this Examiner's amendment.

Reasons for Allowance

- 1. Claims 1-2 and 7 are allowed in view of the submission of a certified English language translation of JP 2000-193453.
- 2. The following is an examiner's statement of reasons for allowance:

None of the prior art of record discloses or suggests a TFT array substrate comprising a semiconductor layer, a thin film transistor formed by a source electrode and a drain electrode, the source electrode and the drain electrode are connected to the semiconductor layer, wherein a width of a crossing portion of the semiconductor layer and a width of a crossing portion of the drain line overlapping with the semiconductor layer that cross an edge line of the gate electrode are made smaller than a width of the drain electrode that is equal to a channel width of the thin film electrode as set forth in claims 1.

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Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dung Nguyen whose telephone number is 571-272-2297. The examiner can normally be reached on Monday-Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert H. Kim can be reached on 571-272-2293. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

DN 07/23/2004

Dung Nguyen
Primary Examiner
Art Unit 2871